

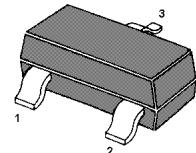
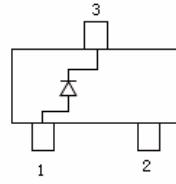


迈拓电子
MAITUO ELECTRONIC

BAS20 SWITCHING DIODE

FEATURES

- Fast Switching Speed
- Surface Mount Package Ideally Suited for Automatic Insertion
- For General Purpose Switching Applications
- High Conductance



Marking: JR

SOT-23

Maximum Ratings @ $T_A=25^\circ\text{C}$

Parameter	Symbol	Limits	Unit
Non-Repetitive Peak reverse voltage	V_{RM}		
DC Blocking Voltage	V_R	150	V
Average Rectified Output Current	I_O	200	mA
Power Dissipation	P_d	250	mW
Thermal Resistance, Junction to Ambient Air	$R_{\theta JA}$	500	$^\circ\text{C}/\text{W}$
Junction temperature	T_J	150	$^\circ\text{C}$
Storage temperature range	T_{STG}	-65-150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS (Tamb=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Reverse breakdown voltage	$V_{(BR)R}$	$I_R = 100\mu\text{A}$	150		V
Reverse voltage leakage current	I_R	$V_R = 150\text{V}$		0.1	μA
Forward voltage	V_F	$I_F = 100\text{mA}$ $I_F = 200\text{mA}$		1 1.25	V
Junction Capacitance	C_J	$V_R = 0\text{V}$, $f = 1\text{MHz}$		5	pF
Reveres recovery time	t_{rr}	$I_F = I_R = 30\text{mA}$, $I_{rr} = 0.1 \times I_R$		50	nS



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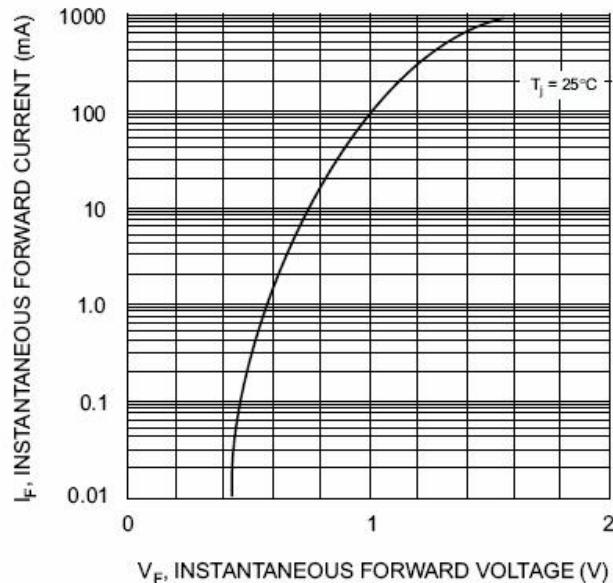


Fig. 1 Forward Characteristics

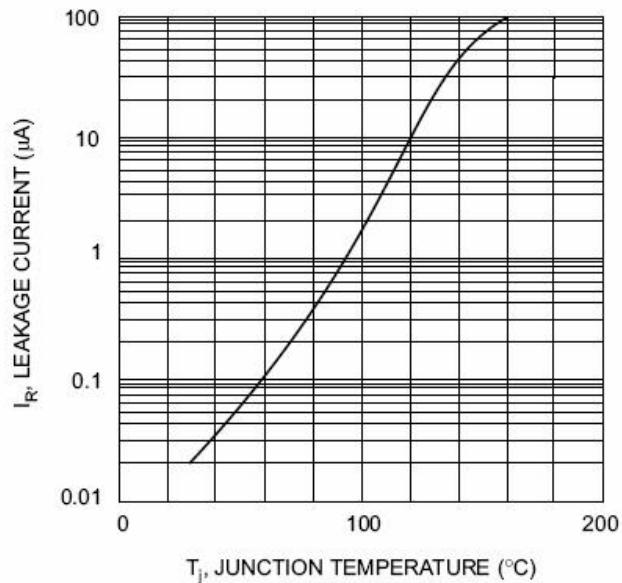


Fig. 2 Leakage Current vs Junction Temperature

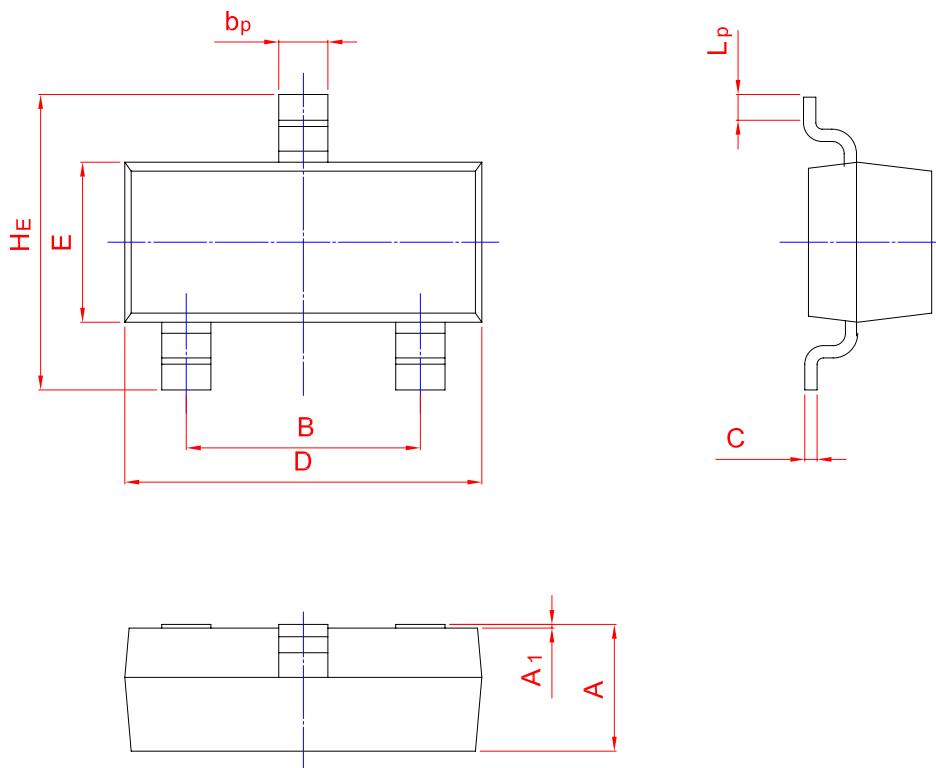


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PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT-23



UNIT	A	B	b _p	C	D	E	H _E	A ₁	L _p
mm	1.40 0.95	2.04 1.78	0.50 0.35	0.19 0.08	3.10 2.70	1.65 1.20	3.00 2.20	0.100 0.013	0.50 0.20